

HLMP-LD63, HLMP-LM63, HLMP-LB63

Precision Optical Performance Red, Green and Blue

New 4mm Standard Oval LEDs



Data Sheet

Description

These Precision Optical Performance Oval LEDs are specifically designed for full color/video and passenger information signs. The oval shaped radiation pattern and high luminous intensity ensure that these devices are excellent for wide field of view outdoor applications where a wide viewing angle and readability in sunlight are essential.

Features

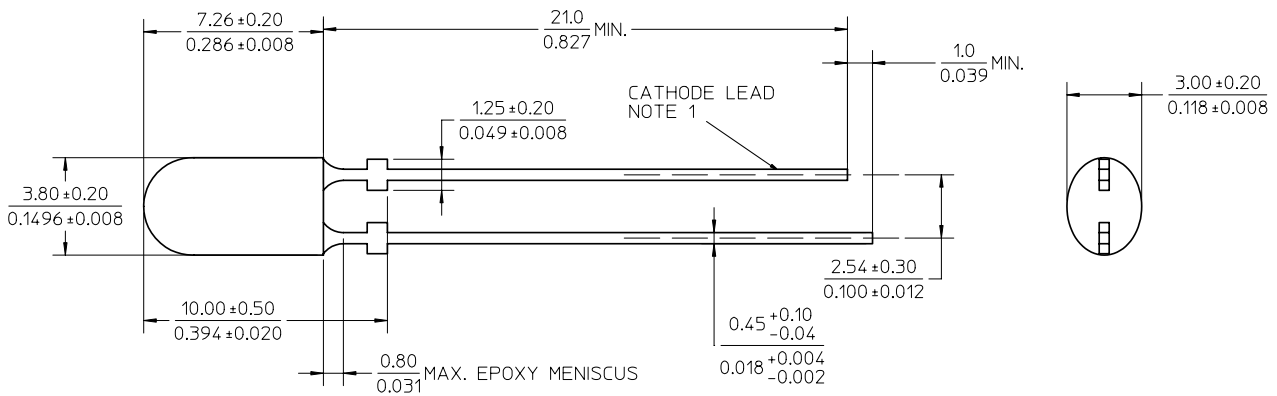
- Well defined spatial radiation pattern
- High brightness material
- Available in red, green and blue color.

Red	AllnGaP	630nm
Green	InGaN	525nm
Blue	InGaN	470nm
- Superior resistance to moisture
- Standoff Package
- Typical viewing angle 50° x100°

Applications

- Full color signs

Package Dimensions



Notes:

All dimensions in millimeters (inches).

Tolerance is ± 0.20 mm unless other specified

For Blue and Green if heat sinking application is required, the terminal for heat sink is anode.

Caution: InGaN devices are Class 1C HBM ESD sensitive per JEDEC Standard. Please observe appropriate precautions during handling and processing. Refer to Application Note AN-1142 for additional details.

Device Selection Guide

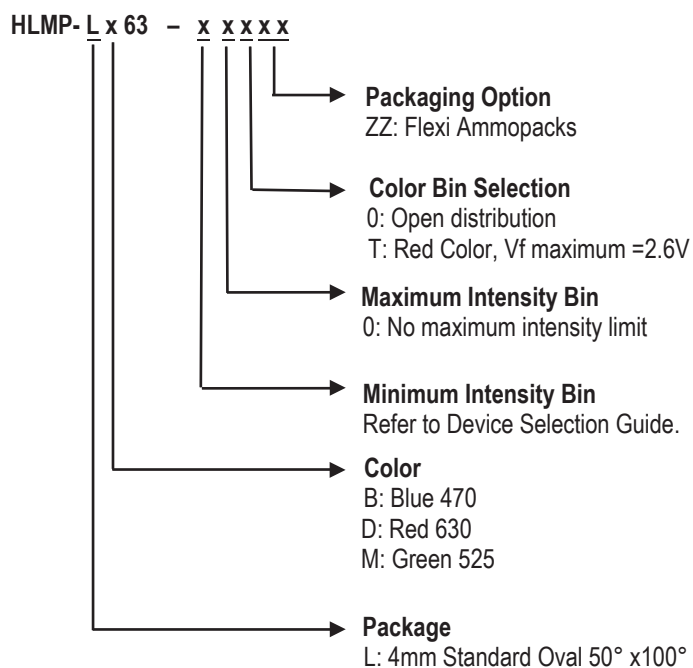
Part Number	Color and Dominant Wavelength λ_d (nm) Typ	Luminous Intensity I_v (mcd) at 20 mA-Min	Luminous Intensity I_v (mcd) at 20 mA-Max
HLMP-LD63-SWTZZ	Red 630	660	1660
HLMP-LM63-X20ZZ	Green 525	1660	4200
HLMP-LB63-PT0ZZ	Blue 470	380	960

Tolerance for each intensity limit is $\pm 15\%$.

Notes:

1. The luminous intensity is measured on the mechanical axis of the lamp package.

Part Numbering System



Absolute Maximum Ratings, $T_A = 25^\circ\text{C}$

Parameter	Red	Blue and Green	Unit
DC Forward Current ^[1]	50	30	mA
Peak Forward Current	100 ^[2]	100 ^[3, 4]	mA
Power Dissipation	130	111	mW
Reverse Voltage	5 ($I_R = 100 \mu\text{A}$)	5 ($I_R = 10 \mu\text{A}$)	V
LED Junction Temperature	130	110	$^\circ\text{C}$
Operating Temperature Range	-40 to +100	-40 to +85	$^\circ\text{C}$
Storage Temperature Range	-40 to +120	-40 to +100	$^\circ\text{C}$

Notes:

1. Derate linearly as shown in Figure 2 and Figure 8.
2. Duty Factor 30%, frequency 1kHz.
3. Duty Factor 10%, frequency 1kHz.
4. For long term performance with minimal light output degradation, drive current below 15mA is recommended for Blue LED.

Electrical / Optical Characteristics, $T_A = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Forward Voltage						
Red	V_F	2.0	2.3	2.6[1]	V	$I_F = 20\text{ mA}$
Green		2.7	3.2	3.7		
Blue		2.7	3.2	3.7		
Reverse Voltage						
Red	V_R	5			V	$I_R = 100\ \mu\text{A}$
Green & blue		5				$I_R = 10\ \mu\text{A}$
Dominant Wavelength [2]						
Red		622	630	634		$I_F = 20\text{ mA}$
Green		520	525	540		
Blue		460	470	480		
Peak Wavelength						
Red	λ_{PEAK}		639		nm	Peak of Wavelength of Spectral Distribution at $I_F = 20\text{ mA}$
Green			516			
Blue			464			
Thermal Resistance						
	$R\theta_{\text{J-PIN}}$		240		$^\circ\text{C/W}$	LED Junction-to pin
Luminous Efficacy [3]						
Red	η_V		155		lm/W	Emitted Luminous Power/Emitted Radiant Power
Green			530			
Blue			65			

Notes:

1. For option –xxTxx, The V_F maximum is 2.6V, refer to VF bin table.
2. The dominant wavelength is derived from the chromaticity Diagram and represents the color of the lamp
3. The radiant intensity, I_e in watts per steradian, may be found from the equation $I_e = I_V/\eta_V$ where I_V is the luminous intensity in candelas and η_V is the luminous efficacy in lumens/watt.
4. For AlInGaP Red, thermal resistance applied to LED junction to cathode lead. For InGaN blue and green, thermal resistance applied to LED junction to anode lead.

AllnGaP Red

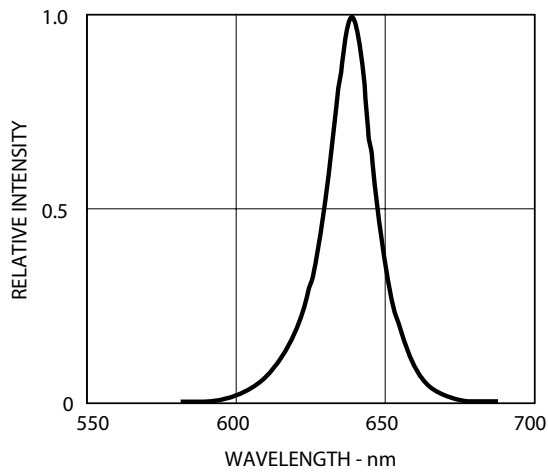


Figure 1. Relative Intensity vs Wavelength

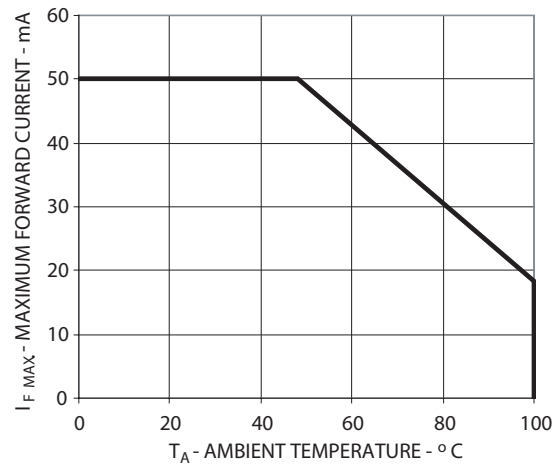


Figure 2. Maximum Forward Current vs Ambient Temperature

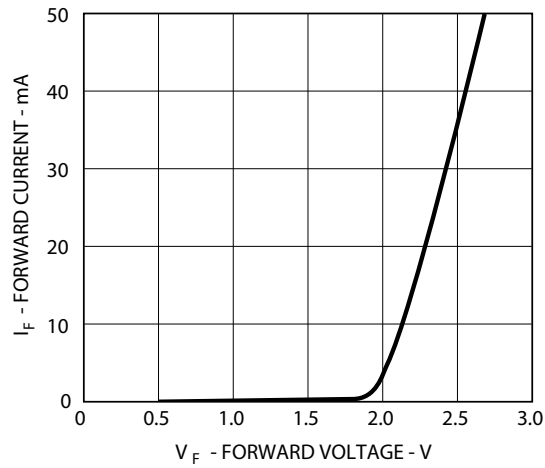


Figure 3. Forward Current vs Forward Voltage

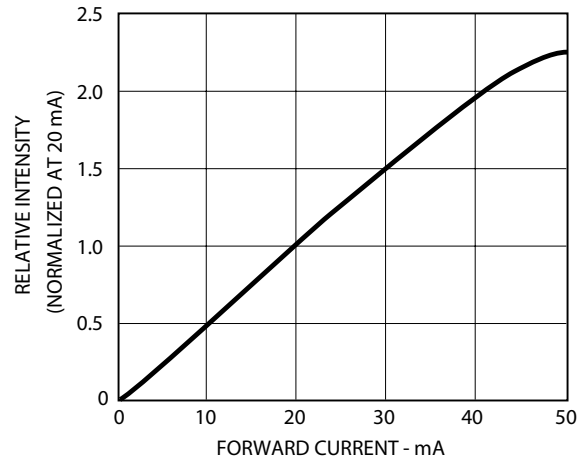


Figure 4. Relative Intensity vs Forward Current

InGaN Blue and Green

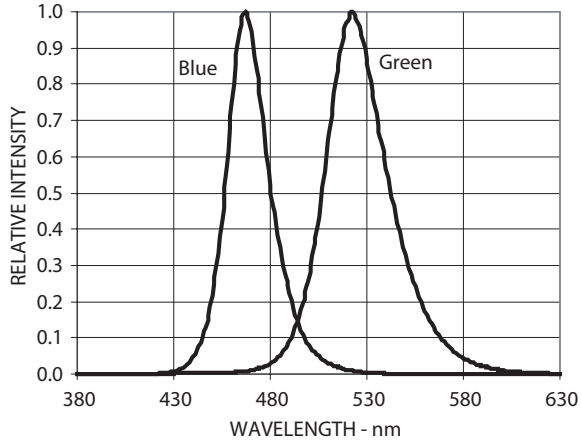


Figure 5. Relative Intensity vs Wavelength

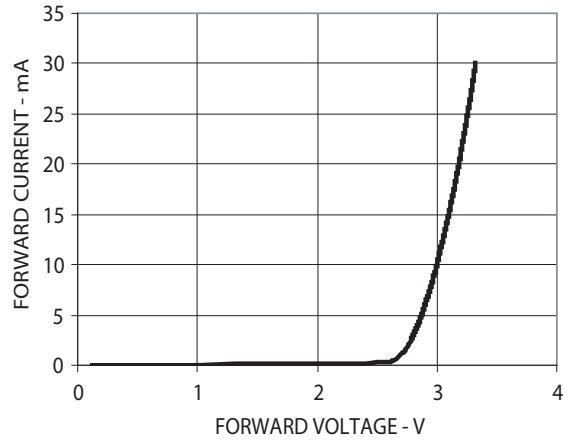


Figure 6. Forward Current vs Forward Voltage

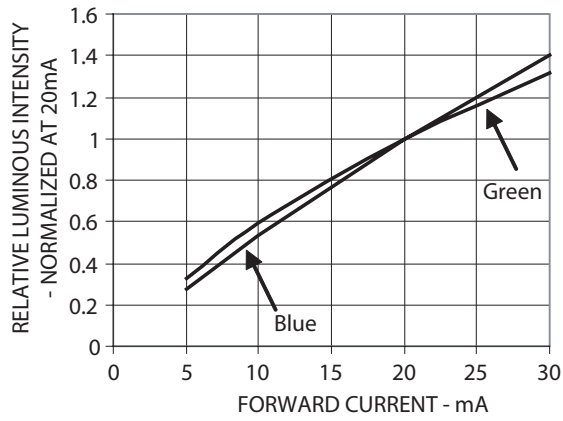


Figure 7. Relative Intensity vs Forward Current

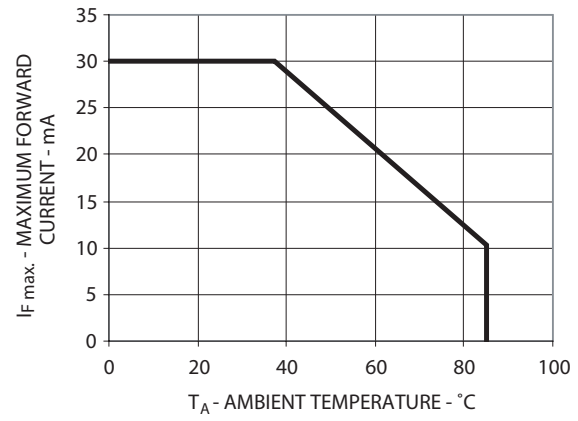


Figure 8. Maximum Forward Current vs Ambient Temperature

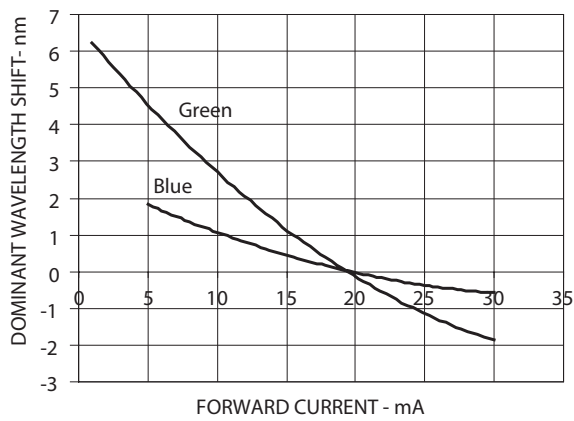


Figure 9. Relative dominant wavelength vs Forward Current

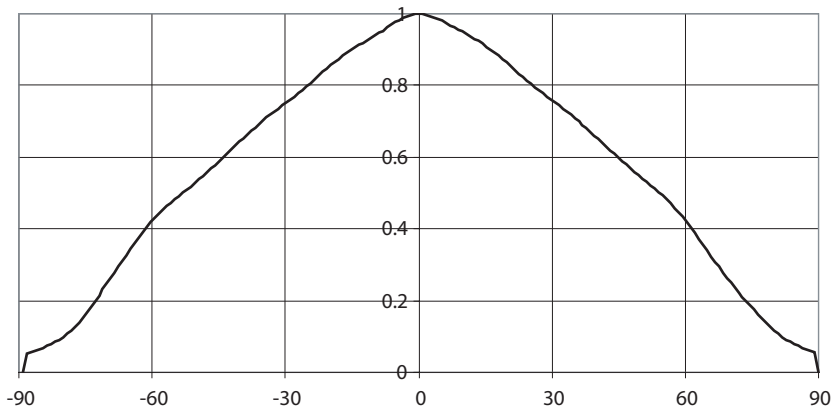


Figure 10. Radiation pattern-Major Axis

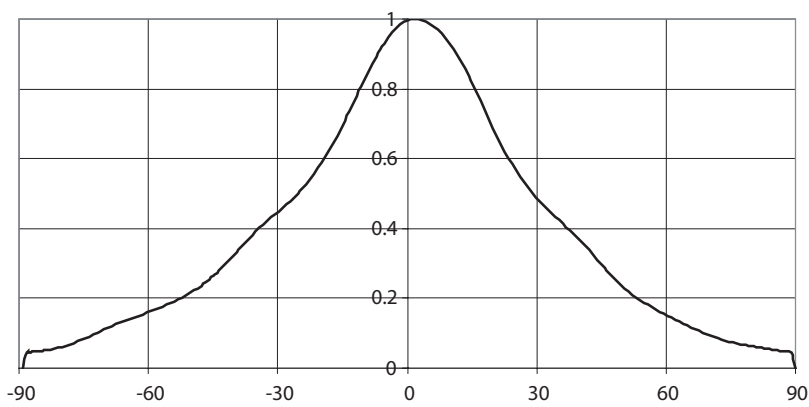


Figure 11. Radiation pattern-Minor Axis

Intensity Bin Limit Table (1.2: 1 Iv Bin Ratio)

Bin	Intensity (mcd) at 20 mA	
	Min	Max
P	380	460
Q	460	550
R	550	660
S	660	800
T	800	960
U	960	1150
V	1150	1380
W	1380	1660
X	1660	1990
Y	1990	2400
Z	2400	2900
1	2900	3500
2	3500	4200

Tolerance for each bin limit is $\pm 15\%$

VF Bin Table (V at 20mA)

Bin ID	Min	Max
VA	2.0	2.2
VB	2.2	2.4
VC	2.4	2.6

Tolerance for each bin limit is ± 0.05

Red Color Range

Min Dom	Max Dom	Xmin	Ymin	Xmax	Ymax
622	634	0.6904	0.3094	0.6945	0.2888
		0.6726	0.3106	0.7135	0.2865

Tolerance for each bin limit is $\pm 0.5\text{nm}$.

Green Color Bin Table

Bin	Min Dom	Max Dom	Xmin	Ymin	Xmax	Ymax
1	520.0	524.0	0.0743	0.8338	0.1856	0.6556
			0.1650	0.6586	0.1060	0.8292
2	524.0	528.0	0.1060	0.8292	0.2068	0.6463
			0.1856	0.6556	0.1387	0.8148
3	528.0	532.0	0.1387	0.8148	0.2273	0.6344
			0.2068	0.6463	0.1702	0.7965
4	532.0	536.0	0.1702	0.7965	0.2469	0.6213
			0.2273	0.6344	0.2003	0.7764
5	536.0	540.0	0.2003	0.7764	0.2659	0.6070
			0.2469	0.6213	0.2296	0.7543

Tolerance for each bin limit is $\pm 0.5\text{nm}$.

Blue Color Bin Table

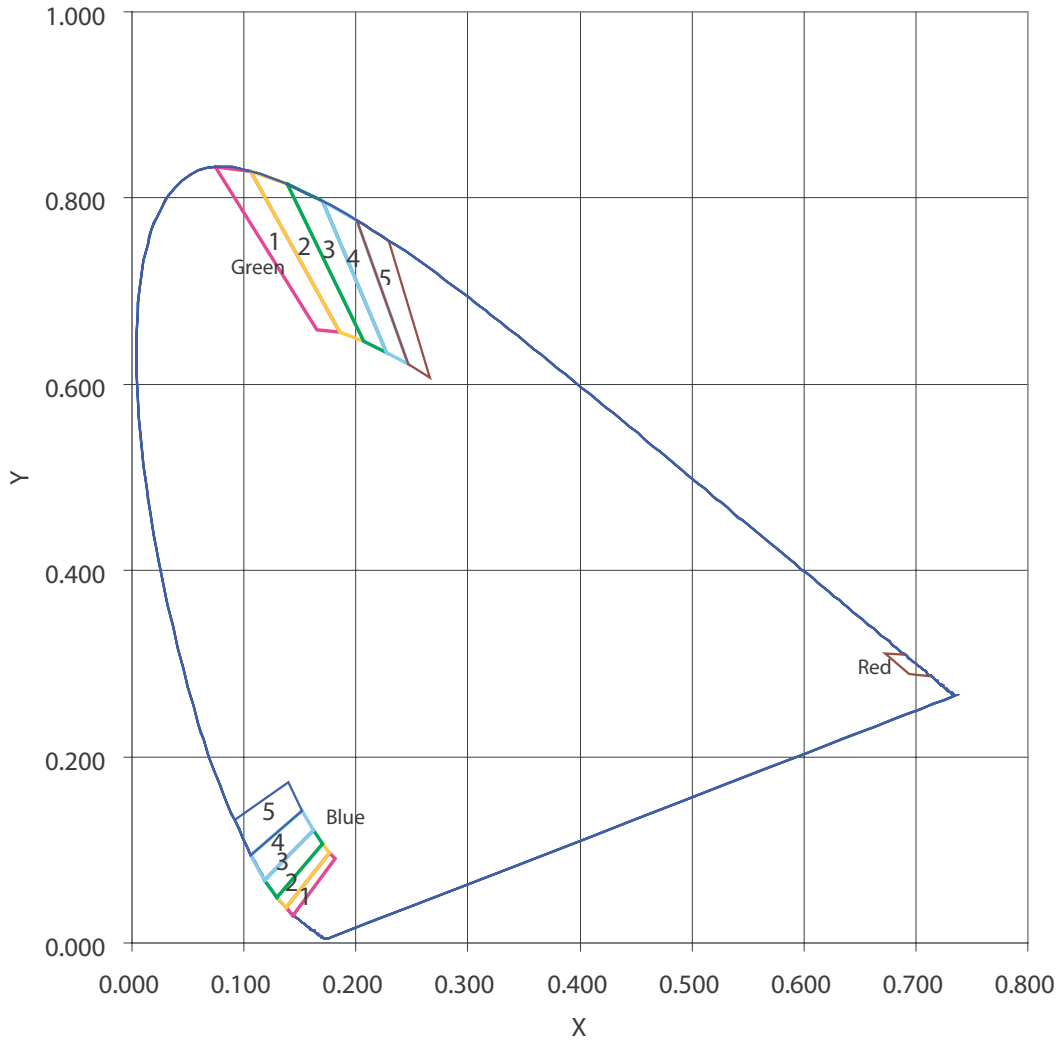
Bin	Min Dom	Max Dom	Xmin	Ymin	Xmax	Ymax
1	460.0	464.0	0.1440	0.0297	0.1766	0.0966
			0.1818	0.0904	0.1374	0.0374
2	464.0	468.0	0.1374	0.0374	0.1699	0.1062
			0.1766	0.0966	0.1291	0.0495
3	468.0	472.0	0.1291	0.0495	0.1616	0.1209
			0.1699	0.1062	0.1187	0.0671
4	472.0	476.0	0.1187	0.0671	0.1517	0.1423
			0.1616	0.1209	0.1063	0.0945
5	476.0	480.0	0.1063	0.0945	0.1397	0.1728
			0.1517	0.1423	0.0913	0.1327

Tolerance for each bin limit is $\pm 0.5\text{nm}$.

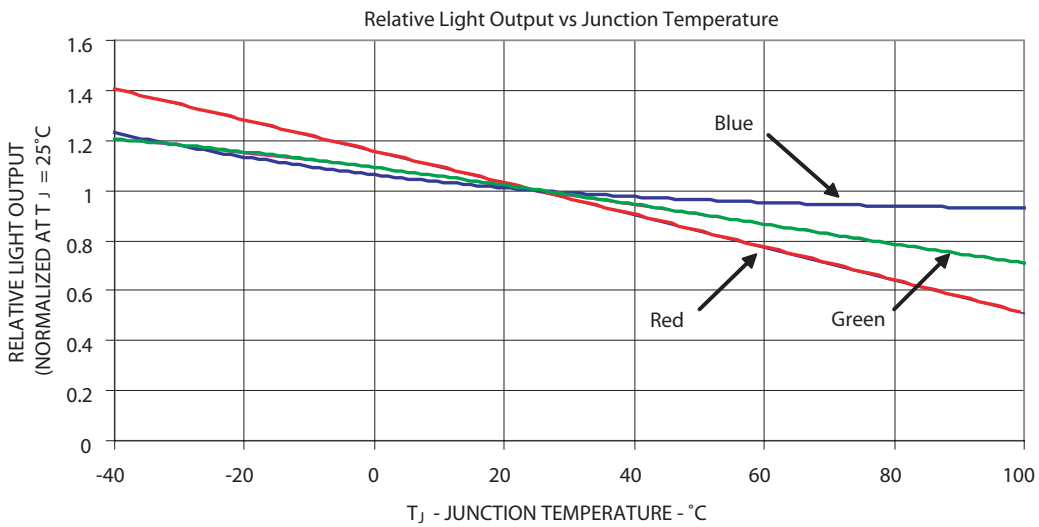
Note:

- All bin categories are established for classification of products. Products may not be available in all bin categories. Please contact your Avago representative for further information.

Avago Color Bin on CIE 1931 Chromaticity Diagram



Relative Light Output vs Junction Temperature



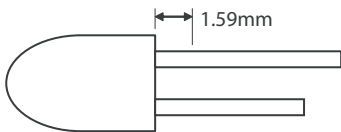
Precautions:

Lead Forming:

- The leads of an LED lamp may be performed or cut to length prior to insertion and soldering on PC board.
- If lead forming is required before soldering, care must be taken to avoid any excessive mechanical stress that induced into the LED package. Otherwise, cut the leads to applicable length after soldering process at room temperature. The solder joint formed will absorb the mechanical stress, due to the lead cutting, from traveling to the LED chip die attach and wirebond.
- For better control, it is recommended to use proper tool to precisely form and cut the leads to applicable length rather than doing it manually.

Soldering condition:

- Care must be taken during PCB assembly and soldering process to prevent damage to the LED component.
- The closest manual soldering distance of the soldering heat source (soldering iron's tip) to the body is 1.59mm. Soldering the LED closer than 1.59mm might damage the LED.



- Recommended soldering condition:

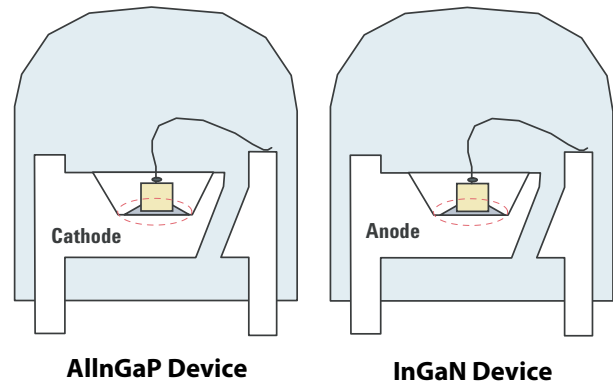
	Wave Soldering	Manual Solder Dipping
Pre-heat temperature	105 °C Max.	-
Preheat time	30 sec Max	-
Peak temperature	250 °C Max.	260 °C Max.
Dwell time	3 sec Max.	5 sec Max

- Wave soldering parameter must be set and maintain according to the recommended temperature and dwell time. Customer is advised to daily check on the soldering profile to ensure that the soldering profile is always conforming to recommended soldering condition.

Note:

1. PCB with different size and design (component density) will have different heat mass (heat capacity). This might cause a change in temperature experienced by the board if same wave soldering setting is used. So, it is recommended to re-calibrate the soldering profile again before loading a new type of PCB.
2. Avago Technologies' high brightness LED are using high efficiency LED die with single wire bond as shown below. Customer is advised to take extra precaution during wave soldering to ensure that the maximum wave temperature is not exceeding 250°C. Over-stressing the LED during soldering process might cause premature failure to the LED due to delamination.

Avago Technologies LED configuration



Note: Electrical connection between bottom surface of LED die and the lead frame material through conductive paste of solder.

- If necessary, use fixture to hold the LED component in proper orientation with respect to the PCB during soldering process.

Note: In order to further assist customer in designing jig accurately that fit Avago Technologies' product, 3D model of the product is available upon request.

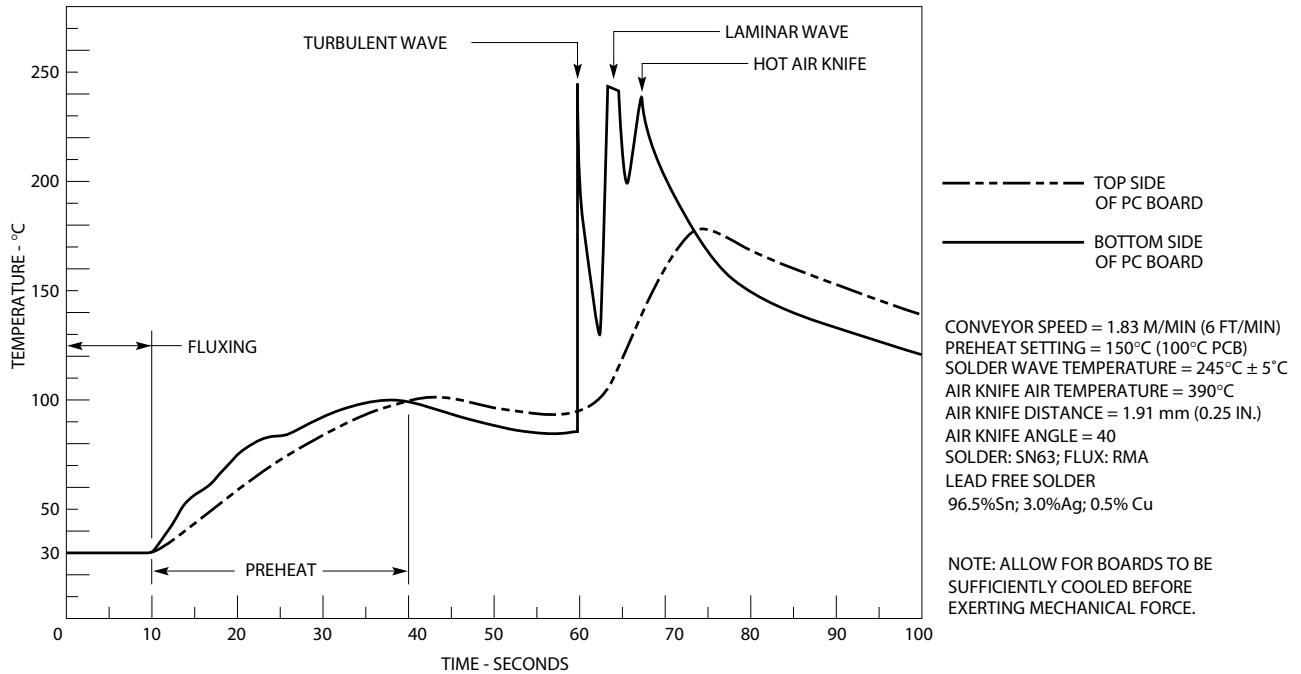
- At elevated temperature, the LED is more susceptible to mechanical stress. Therefore, PCB must allowed to cool down to room temperature prior to handling, which includes removal of jigs, fixtures or pallet.
- Special attention must be given to board fabrication, solder masking, surface plating and lead holes size and component orientation to assure the solderability.
- Recommended PC board plated through holes size for LED component leads.

LED component lead size	Diagonal	Plated through hole diameter
0.457 x 0.457 mm (0.018 x 0.018 inch)	0.646 mm (0.025 inch)	0.976 to 1.078 mm (0.038 to 0.042 inch)
0.508 x 0.508 mm (0.020 x 0.020 inch)	0.718 mm (0.028 inch)	1.049 to 1.150 mm (0.041 to 0.045 inch)

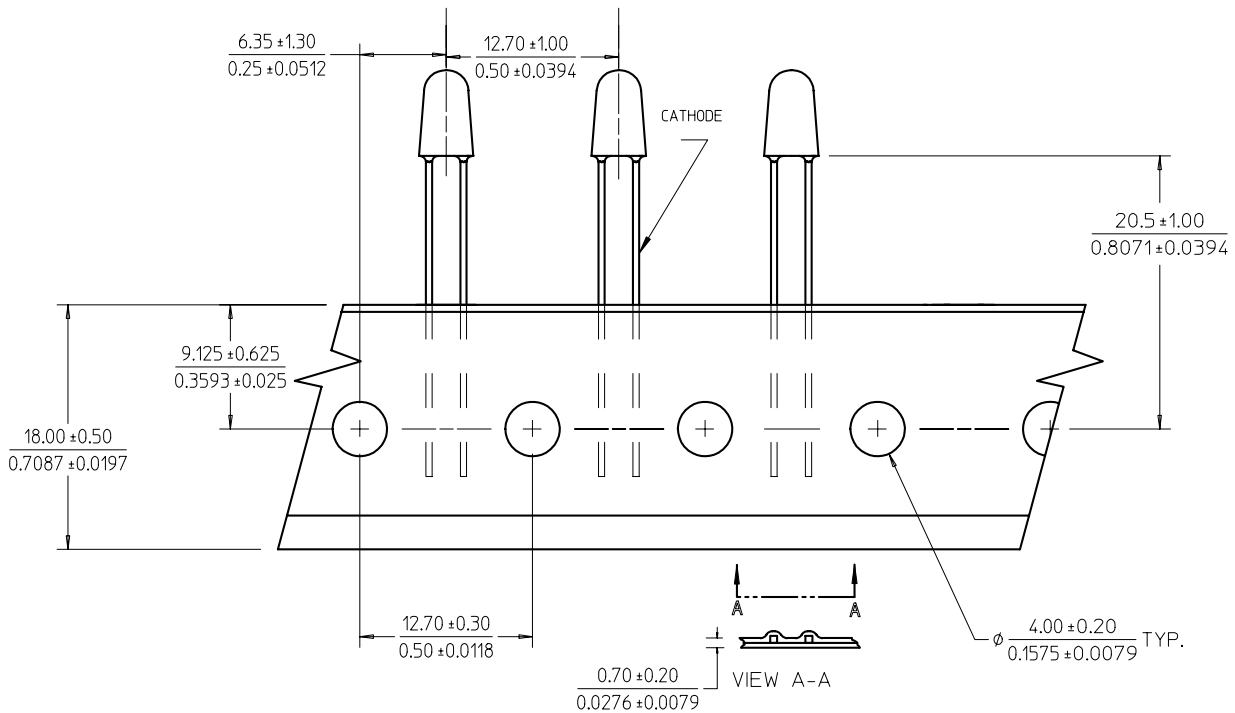
- Under sizing of plated through hole can lead to twisting or improper LED placement during auto insertion. Over sizing plated through hole can lead to mechanical stress on the epoxy lens during clinching.

Note: Refer to application note AN1027 for more information on soldering LED components.

Recommended Wave Soldering Profile

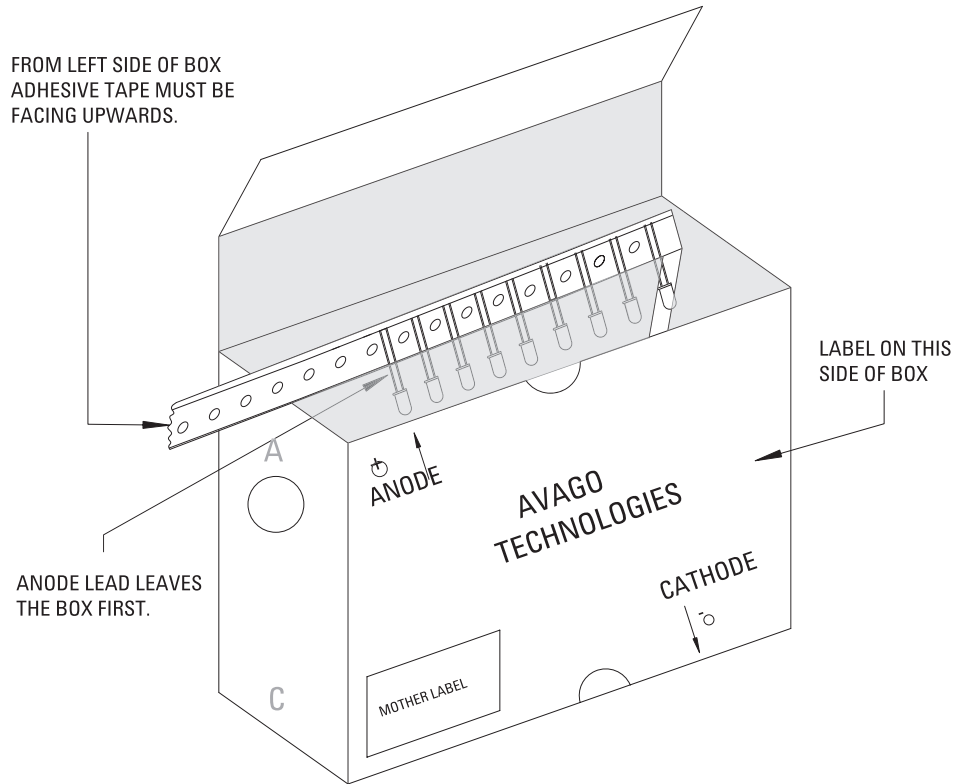


Ammo Packs Drawing



Note: The ammo-packs drawing is applicable for packaging option -DD & -ZZ and regardless standoff or non-standoff

Packaging Box for Ammo Packs



Note: For InGaN device, the ammo pack packaging box contain ESD logo

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AV02-0076EN - January 22, 2007

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